

HI-8585, HI-8586

July 1999

ARINC 429 LINE DRIVER

DESCRIPTION

The HI-8585 and HI-8586 are CMOS integrated circuits designed to directly drive the ARINC 429 bus in an 8 pin package. Two logic inputs control a differential voltage between the output pins producing a +10 volt One, a -10 volt Zero, and a 0 volt Null.

The CMOS/TTL control inputs are translated to ARINC specified amplitudes using on board zeners. A logic input is provided to control the slope of the differential output signal. Timing is set by on-chip resistor and capacitor and tested to be within ARINC requirements.

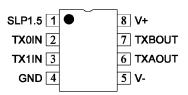
The HI-8585 has 37.5 ohms in series with each line driver output. The HI-8586 provides the option to bypass most of the output resistance so that series protection circuits can add their resistances.

The HI-8585 or the HI-8586 along with the HI-8588 line receiver offer the smallest options available to get on and off the ARINC bus.

FEATURES

- Direct ARINC 429 line driver interface in a small package
- On-chip zener to set output levels
- On-chip line driver slope control and selection by logic input
- Low current 12 to 15 volt supplies
- CMOS / TTL logic pins
- Plastic and ceramic package options surface mount and DIP
- Mil processing available

PIN CONFIGURATION



SUPPLY VOLTAGES

V+ = 12V to 15V V- = -12V to -15V

FUNCTION TABLE

TX1IN	TXOIN	SLP1.5	TXAOUT	TXBOUT	SLOPE
0	0	Х	0 V	0 V	N/A
0	1	0	-5 V	5V	10µs
0	1	1	-5 V	5V	1.5µs
1	0	0	5V	-5 V	10µs
1	0	1	5 V	-5 V	1.5µs
1	1	Х	0 V	0 V	N/A

PIN DESCRIPTION TABLE

PIN	SYMBOL	FUNCTION	DESCRIPTION
1	SLP1.5	LOGIC INPUT	CM OS OR TTL, V+IS OK
2	TXOIN	LOGIC INPUT	CM OS OR TTL
3	TX1IN	LOGIC INPUT	CM OS OR TTL
4	GND	POWER	GROUND
5	V-	POWER	-12 TO -15 VOLTS
6	TXAOUT	LOGIC OUTPUT	LINE DRIVER TERMINAL A
7	TXBOUT	LOGIC OUTPUT	LINE DRIVER TERMINAL B
8	V+	POWER	+12TO +15 VOLTS

FUNCTIONAL DESCRIPTION

Figure 1 is a block diagram of the line driver. The +5V and -5V levels are generated internally using on-chip zeners. Currents for slope control are set by zener voltages across on-chip resistors.

The TX0IN and TX1IN inputs receive logic signals from a control transmitter chip such as the HI-6010 or HI-8282. TXAOUT and TXBOUT hold each side of the ARINC bus at Ground until one of the inputs becomes a One. If for example TX1IN goes high, a charging path is enabled to 5V on an "A" side internal capacitor while the "B" side is enabled to -5V. The charging current is selected by pin 1, SLP1.5. If pin 1 is high, the capacitor is nominally charged from 10% to 90% in 1.5µs. If pin 1 is low, the rise and fall times are 10µs.

A unity gain buffer receives the internally generated slopes and differentially drives the ARINC line. Current is limited by the series output resistors at each pin. There are no fuses at the outputs of the HI-8585 as exists on the HI-8382.

The HI-8585 has 37.5 ohms in series with each output. The HI-8586 has 10 ohms in series. The HI-8586 is for applications where more series resistance is added externally, typically for lightning protection devices.

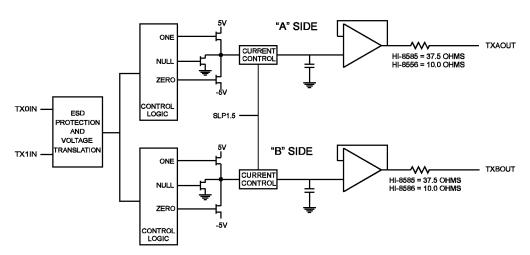


FIGURE 1 - LINE DRIVER BLOCK DIAGRAM

APPLICATION INFORMATION

Figure 2 shows a possible application of the HI-8585/86 interfacing an ARINC transmit channel from the HI-6010.

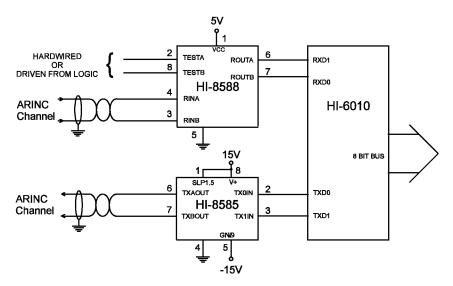


FIGURE 2 - APPLICATION DIAGRAM

HI-8585, HI-8586

ABSOLUTE MAXIMUM RATINGS

Voltages referenced to Ground

Supply voltages V+
DC current per input pin+10mA
Power dissipation at 25°C plastic DIL1.0W, derate 10mW/°C ceramic DIL0.5W, derate 7mW/°C
Solder Temperature275°C for 10 sec
Storage Temperature65°C to +150°C

RECOMMENDED OPERATING CONDITIONS

Supply Voltages V++12V ± 5% or +15V ±10% V12V ± 5% or -15V ±10%
Temperature Range Industrial Screening40°C to +85°C Hi-Temp Screening55°C to +125°C Military Screening55°C to +125°C

NOTE: Stresses above absolute maximum ratings or outside recommended operating conditions may cause permanent damage to the device. These are stress ratings only. Operation at the limits is not recommended.

DC ELECTRICAL CHARACTERISTICS

V+ = +12V to +15V, V- = -12V to -15V, T_A = Operating Temperature Range (unless otherwise stated)

PARAMETERS	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Input voltage (TX1IN, TX0IN, SL1.5)						
high	V _{IH}		2.1	-	V+	volts
low	V _{IL}		-	-	0.5	volts
Input current (TX1IN, TX0IN, SL1.5)						
source	l I _{IH}	V _{IN} = 0 V	_	-	0.1	μΑ
sink	1 IL	, V _{IN} = 5 V	-	-	0.1	μΑ
ARINC output voltage						
one or zero	V _{DOUT}	no load & magnitude at pin	4.50	5.00	5.50	volts
null	V _{NOUT}		-0.25	-	0.25	volts
Operating supply current		pin 1 = V+				
V+	l _{DD}	pins 2 & 3 = 0V; no load	_	6.0	12.0	mA
V-	l EE	pins 2 & 3 = 0V; no load	-12	-6.0	-	mA
ARINC output impedance	Z _{OUT}	Note 1				
HI-8585			_	37.5	-	ohms
HI-8586			-	10	-	ohms

NOTE:

1. The output resistance is checked by measuring the momentary short circuit current at each ARINC output pin.

HI-8585, HI-8586

AC ELECTRICAL CHARACTERISTICS

V+ = 15.0V, V- = -15V, $T_A = Operating Temperature Range (unless otherwise stated)$

PARAMETERS	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Line Driver propagation delay Output high to low Output low to high	t phlx t plhx	defined in Figure 3, no load	-	500 500	-	ns ns
Line Driver transition times Output high to low Output low to high	t fx t rx	pin 1 = logic 1 pin 1 = logic 1	1.0 1.0	1.5 1.5	2.0 2.0	μs μs
Input capacitance (1) logic	C _{IN}		-	-	10	pF

Notes:

1. Guaranteed but not tested

HI-8585 PACKAGE THERMAL CHARACTERISTICS

MAXIMUM ARINC LOAD

PACKAGE STYLE 1	ARINC 429	SUPPLY CURRENT (mA) 2			JUNCTION TEMP, Tj (°C)				
PACKAGE STILE	DATA RATE	Ta = 25°C	Ta = 85°C	Ta=125°C		Ta=125°C			
8 Lead Plastic DIP	Low Speed 3	16.8	17.2	16.9	58	116	157		
o Lead I lague Dil	High Speed 4	27.3	26.7	25.9	75	132	169		
8 Lead Plastic SOIC ⁵	Low Speed	17.4	17.5	16.9	68	126	166		
o Leau Flasiic SOIC	High Speed	27.6	27.1	25.9	97	147	186		
8 Lead Plastic SOIC ⁶	Low Speed	17.1	17.2	16.7	52	110	151		
	High Speed	27.3	27.1	26.2	57	112	157		

TXAOUT and TXBOUT Shorted to Ground 7,8

PACKAGE STYLE 1	ARINC 429	SUPPL	Y CURREN	T (mA) ²	JUNCTION TEMP, Tj (°C)				
PACKAGE STYLE	DATA RATE	Ta = 25°C	Ta = 85°C	Ta=125°C	Ta = 25°C	25°C Ta = 85°C 31 181 35 181 67 191	Ta=125°C		
O L and Dinatic DID	Low Speed 3	53.6	50.7	52.2	131	181	217		
8 Lead Plastic DIP	High Speed 4	46.9	38.7	42.5	135	181	219		
	Low Speed	46.4	47.6	68.1	167	191	221		
8 Lead Plastic SOIC ⁵	High Speed	42.1	43.8	67.1	177	212	223		
8 Lead Plastic SOIC ⁶	Low Speed	48.5	45.6	46.1	112	161	186		
	High Speed	46.8	41.1	40.5	116	168	197		

Notes:

- 1. All data taken on devices soldered to single layer copper PCB (3" X 4.5" X .062").
- 2. At 100% duty cycle, 15V power supplies. For 12V power supplies multiply all tabulated values by 0.8.
- 3. Low Speed: Data Rate = 12.5 Kbps, Load: R = 400 Ohms, C = 30 nF.
- 4. High Speed: Data Rate = 100 Kbps, Load: R = 400 Ohms, C = 10 nF. Data not presented for C = 30 nF as this is considered unrealistic for high speed operation.
- 5. 8 Lead Plastic SOIC (Thermally enhanced with built in heat sink). Heat sink not soldered to the PCB.
- 6. 8 Lead Plastic SOIC (Thermally enhanced with built in heat sink). Heat sink soldered to the PCB.
- 7. Similar results would be obtained with TXAOUT shorted to TXBOUT.
- 8. For applications requiring survival with continuous short circuit, operation above Tj = 175°C is not recommended.

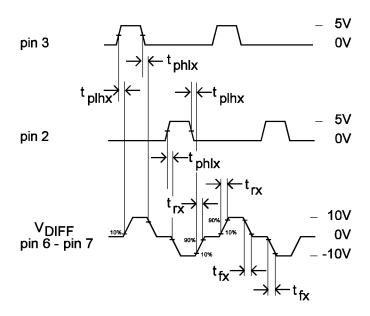


FIGURE 3 - LINE DRIVER TIMING

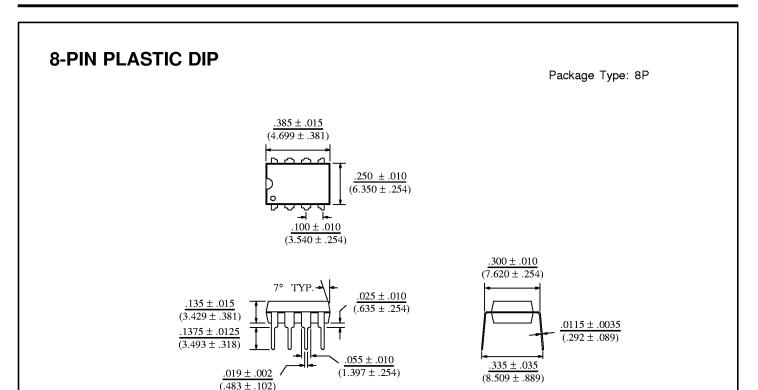
ORDERING INFORMATION

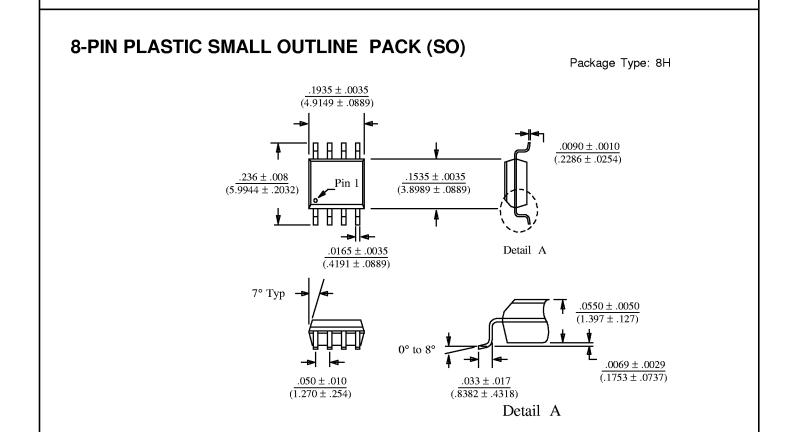
PART NUMBER	PACKAGE DESCRIPTION	TEMPERATURE RANGE	FLOW	BURN IN	LEAD FINISH
HL8585PDI	8 PIN PLASTIC DIP	-40°C TO +85°C		NO	SOLDER
HF8585PSI	8 PIN PLASTIC SO	-40°C TO +85°C		NO	SOLDER
HF8585CDI	8 PIN CERAMIC SIDE BRAZED DIP	-40°C TO +85°C		NO	GOLD
HI-8585CDT	8 PIN CERAMIC SIDE BRAZED DIP	-55°C TO +125°C	Т	NO	GOLD
HI-8585CDM	8 PIN CERAMIC SIDE BRAZED DIP	-55°C TO +125°C	М	YES	SOLDER
HI-8585CRI	8 PIN CERDIP	-40°C TO +85°C	I	NO	SOLDER
HI-8585CRT	8 PIN CERDIP	-55°C TO +125°C	Т	NO	SOLDER
H-8585CRM	8 PIN CERDIP	-55°C TO +125°C	М	YES	SOLDER
HF8586PDI	8 PIN PLASTIC DIP	-40°C TO +85°C	1	NO	SOLDER
HI-8586PDT	8 PIN PLASTIC DIP	-55°C TO +125°C	Т	NO	SOLDER
HL8586PSI	8 PIN PLASTIC SO	-40°C TO +85°C		NO	SOLDER
HI-8586PST	8 PIN PLASTIC SO	-55°C TO +125°C	Т	NO	SOLDER
HI-8586CDI	8 PIN CERAMIC SIDE BRAZED DIP	-40°C TO +85°C	ı	NO	GOLD
HI-8586CDT	8 PIN CERAMIC SIDE BRAZED DIP	-55°C TO +125°C	Т	NO	GOLD
HI-8586CDM	8 PIN CERAMIC SIDE BRAZED DIP	-55°C TO +125°C	М	YES	SOLDER
HI-8586CRI	8 PIN CERDIP	-40°C TO +85°C	ı	NO	SOLDER
HI-8586CRT	8 PIN CERDIP	-55°C TO +125°C	Т	NO	SOLDER
HF8586CRM	8 PIN CERDIP	-55°C TO +125°C	М	YES	SOLDER



HI-8585 / HI-8586 PACKAGE DIMENSIONS

inches (millimeters)







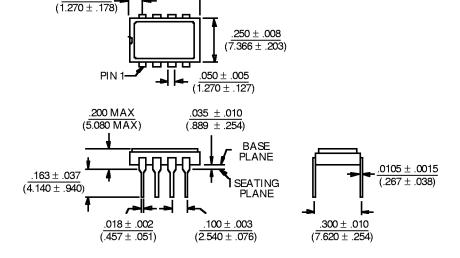
HI-8585 / HI-8586 PACKAGE DIMENSIONS

inches (millimeters)

8-PIN CERAMIC SIDE-BRAZED DIP

.050 ± .007

Package Type: 8C



 $\frac{.405 \pm MAX}{(10.287 \pm MAX)}$

8-PIN CERDIP

Package Type: 8D

